ABSTRACT - The main aim of this paper is to analyse the performance of an optical source designed starting from the external feedback of a travelling wave optical amplifier (TWOA). The proposed structure is analysed using a computer model based on travelling wave and carrier equations. From the performed simulations characteristic curves (output power, spectral quality, etc) have been obtained, which show the high performances that this type of source can offer in optical fibre communication systems. On the other hand, we can infer interesting conclusions from the obtained results. This will enable us to achieve optimal designs regarding maximum optical power and spectral quality values.

1. Introduction

The great advance that the use of optical fibres has meant in long haul transmission links, has considerably driven the development of optoelectronic devices based on gallium arsenide technology. A good example of these are found in present InGaAs semiconductor lasers [1], [2].

However, in spite of the high technological standard, totally monochromatic laser sources have not been obtained yet. This aspect is important both in coherent transmission systems (PSK and FSK) and in those where wavelength multiplexation is used.

In this paper we suggest, as an optical source, the use of a structure basically composed of a travelling wave semiconductor optical amplifier with external feedback by means of a monomode optical fibre section. The design also includes two optical devices: an isolator and a beam splitter. Our fundamental aim is to show the feasibility of this design as a high performance laser source.

In the following section the block diagram of the optical source is shown, specifying all the elements included in it. The fundamental equations describing the working principle of the feedback optical amplifier is commented in section 3. In section 4 we present the results obtained from computer simulations. Specifically, curves showing the light-current characteristic and the spectral quality of the emitted optical power have been obtained. Special emphasis is laid on the importance that both TWOA’s length and the feedback factor have on the performances of the optical source. From all this, design conditions arise from which optimal behaviours can be found. In section 5 the main conclusions are summarized.

2. Implementation of travelling wave optical amplifier with external feedback

In Fig.1 the configuration and the elements of the optical source that we are to characterize can be seen. Now we will describe the main function of each of them, leaving for the next section the main equations and some practical aspects.

The optical amplifier (TWOA) is the element capable of contributing the necessary gain to the structure. We have denominated $G_s$ its simple pass gain, which we suppose compensates for all kind of losses not included a priori in the configuration shown in Fig.1 (for example, possible losses of different couplings, small losses in the fibre section, etc). In practical situations we use near travelling wave optical amplifiers, although, due to the very low
reflectivities (lower than $10^{-4}$), its influence is irrelevant [3].

The mission of the ideal optical power splitter (BS) would be to break up the power emitted by the amplifier ($P_a$) in two parts: one delivered in the output of the structure ($P_{out}$) and the other one is feedback ($P_c$). We have denominated $a_r$ the fraction of optical power which is feedback and, consequently, $(1-a_r)$ the fraction at the output of the source.

The external optical feedback is done by means of a monomode optical fibre section. Due to the wide gain bandwidth and the low attenuation of present fibres, we can suppose that this section neither distorsionates nor attenuates the feedback optical power. However, its length has to be as short as possible and must also fulfil the adequate phase conditions so that the total increment of the phase of the electrical field along an oscillation will be nil. This condition is set by the lengths and the refraction indexes both the TWOA and of the optical fibre. In that way the resonant modes of the structure and the corresponding spectral distribution of the output optical power will be determined.

The external feedback allows us to include an optical isolator (OI) in order to eliminate the spontaneous emission which escapes through the left face of the amplifier. Thus reducing its saturation level and improving both the noise figure and the spectral quality of the optical source. The state of art of technology supplies us with optical isolators with nil insertion losses and with isolation losses greater than 40 dB.

3. Basic equations

Taking into account the configuration of Fig.1 and the function of each one of the blocks described in the previous section, now we are going to analyse the set of equations that characterize the optical source. As one of the model we will suppose that the source works in steady state conditions and above the oscillation threshold.

The optical power at the output of the amplifier can be expressed as

$$P_b = G_s P_a$$  \hspace{1cm} (1)

where $P_a$ is the input power and $G_s$ the single pass gain of the TWOA. On the other hand, the BS splits the $P_b$ power in the following fractions:

$$P_{out} = (1-a_r) P_b$$ \hspace{1cm} (2)

$$P_c = a_r P_b$$ \hspace{1cm} (3)

where $a_r$ is the fraction of feedback optical power as we have already indicated in section 3. We consider that both the optical fibre sectio and the OI don't present any losses (if this is not the case in a practical situation, we could demand an additional small increment to the $G_s$ value in our model). Then

$$P_b = P_c$$ \hspace{1cm} (4)

By means of the equation set (1-4), it is easy to establish the next fundamental relations:

$$G_s = \frac{1}{a_r}$$ \hspace{1cm} (5)

$$P_{out} = (1- \frac{1}{G_s}) P_b$$ \hspace{1cm} (6)

Equation (5) implies that the single pass gain of the amplifier is determined by the chosen value of $a_r$. Actually, this equation is the amplitude condition that any oscillator has to fulfil (the value $a_r$ finds its corresponding one in the facet reflectivities of a simetric FP cavity laser). The numerical simulations that we have done demonstrate that, in order to obtain best performances of the optical source, the value of $a_r$ has to lie between 0.3 and 0.4. Consequently, the amplifier single pass gain has values lying between 2.5 and 3.3. If we have already determined the value of $G_s$, equation (6) implies that the output power $P_{out}$ is determined by the $P_b$ power. This magnitude depends on the bias current ($I$) and on a set of physical and geometrical parameters. Then, it is necessary to know the internal amplification mechanism of the light. Due to the saturation process that the amplifier experiences (nonlinear behaviour) the co-
responding analysis of the two fundamental equations that took part (the rate equations for the photons and carrier densities) is extremely complicated. They are:

\[
\frac{dS(z,\lambda_1)}{dz} = \frac{\Gamma S(z,\lambda_1)}{v_{sp}} - \frac{N(z)}{v_{sp}^2} + g(z,\lambda_1)S(z,\lambda_1) \tag{7}
\]

\[
\frac{dN(z)}{dz} = \frac{1}{\text{VdWL}_{OA}} - \frac{N(z)}{v_{sp}^2} \sum_i g_m(z,\lambda_i)S(z,\lambda_i) \tag{8}
\]

In these equations \(S(z,\lambda_i)\) represents, for the \(i\)-mode with wavelength \(\lambda_i\), the photon density \((\text{cm}^{-2})\) in the \(z\)-coordinate (amplification axis). \(N(z)\) is the carrier density \((\text{cm}^{-3})\), which decreases from \(z=0\) to \(z=\text{LoA}\). The magnitude \(I/(\text{W}.\text{LoA})\) represents the uniform injected current density \((\text{kA/cm}^2)\) along the active layer, which has a width \(W\) and a length \(\text{LoA}\) (an ideal efficiency of the pumping current \(I\) has been supposed ). The constants \(\Gamma, \beta, \tau_{sp}\) and \(v\) are typical of the semiconductor material. They are the carrier lifetime and the propagation velocity in the active layer, respectively. We denote \(q\) as the nominal electron charge.

On the other hand, the net gain per length unit, \(g(z,\lambda_i)\), can be related to the intrinsic gain of the semiconductor material, \(g_m(z,\lambda_i)\), [4], through

\[
g(z,\lambda_1) = \Gamma g_m(z,\lambda_1) - \alpha \tag{9}
\]

where \(\alpha\) \((\text{cm}^{-1})\) is the material linear losses coefficient (scattering and other losses mechanisms). The gain \(g_m(z,\lambda_i)\) is

\[
g_m(z,\lambda_i) = \sigma \cdot (N(z)-N_o) - \chi \cdot (\lambda_1-\lambda_p)^2 \tag{10}
\]

where \(\sigma, \chi, N_o\) and \(\lambda_p\) are important parameters of the material which represent the differential gain parameter, a parabolic parameter, the transparency carrier density and the peak wavelength, respectively.

In order to solve the nonlinear and coupled set of equations given by (7) and (8), the authors of this paper have used the computer model proposed by D.Marcuse in [4]. It is a very powerful technique because it takes into account both the saturation effect and the spatial variation of the carrier density along the \(z\)-axis. This model has been applied to the proposed structure taking into account the equation set (1-6). Essentially, these equations correspond to the boundary conditions of the differential equations (7) and (8). For example, the photon densities at \(z=0\) and \(z=\text{LoA}\) are proportional to the powers \(P_a\) and \(P_b\). It is easy to demonstrate that the minimum pumping current to reach the oscillation condition of the structure (threshold current), is

\[
I_{th} = \frac{\text{qVdL}_{OA}}{\tau_{sp} \alpha + \frac{1}{\text{LoA}} |N_{\pi}^2|} \tag{11}
\]

In all the simulations done we always suppose values of the current \(I\) above \(I_{th}\).

4. Performances of the designed optical source

The model developed in [4] has been fitted to the structure shown in Fig.1 and has been numerically solved using the values that we present in table I. All of them are the typical values that a TWOA has, excepting \(\alpha=0.32\), the length of the fibre section \(\text{Lo}_f=666\mu\text{m}\) and its refraction index \(n_{\text{in}}=1.5\) (the refraction index of the semiconductor active layer is denoted \(n_{\text{TW}}\)).

As we show next, it is important to choose a suitable value of the TWOA's length. It can be seen in Fig.2 in which the output power \(P_{out}\) as a function of the optical amplifier's length is represented, for three different values of the bias current. Obviously, the higher the bias current the greater output power obtained. As in a FP lasers, always exists a length for which maximum power is obtained.

In order to analyse the spectral quality of the emitted light, it is necessary to define a merit figure. Then, we define the spectral quality (SQ) as

\[
\text{SQ(dB)} = 10 \log \left( \frac{P_o}{P_i} \right) \tag{11}
\]
Figure 1

Figure 3

Figure 2

Figure 4

Table 1

<table>
<thead>
<tr>
<th>Symbol</th>
<th>Value</th>
</tr>
</thead>
<tbody>
<tr>
<td>W</td>
<td>2.5 μm</td>
</tr>
<tr>
<td>d</td>
<td>0.1 μm</td>
</tr>
<tr>
<td>Γ</td>
<td>0.18</td>
</tr>
<tr>
<td>α</td>
<td>30 cm⁻¹</td>
</tr>
<tr>
<td>σ</td>
<td>2.5·10⁻¹⁶ cm²</td>
</tr>
<tr>
<td>γ</td>
<td>6.5·10¹² cm⁻³</td>
</tr>
<tr>
<td>τₚ</td>
<td>2.14 ns</td>
</tr>
<tr>
<td>Nₒ</td>
<td>10⁸ cm⁻³</td>
</tr>
<tr>
<td>λₚ</td>
<td>1.52 μm</td>
</tr>
<tr>
<td>β</td>
<td>10⁻⁵</td>
</tr>
<tr>
<td>nₒA</td>
<td>4</td>
</tr>
<tr>
<td>aₜ</td>
<td>0.32</td>
</tr>
<tr>
<td>nₒF</td>
<td>1.5</td>
</tr>
<tr>
<td>LₒF</td>
<td>666 μm</td>
</tr>
</tbody>
</table>
where $P_0$ and $P_1$ are the optical powers belonging to the central and the first adjacent modes, respectively. In Fig.3 we have plotted the SQ as a function of the TWOA's length for three different bias currents. Again we find that optimal lengths exist. However, it must be pointed out the fact that, for a given current, the value of $L_{OA}$ that maximizes $P_{out}$ is not the same one that maximizes SQ. For example, for a 25 mA current we find a maximum optical power if $L_{OA}=140\mu$m. Instead, for the same current, the length that maximizes SQ is $L_{OA}=90\mu$m. This interesting trade off has to be solved depending on the concrete application. Anyway, we can see that, for lengths around $100\mu$m and reasonable currents (some ten mA's), output powers over 1.5mW can be obtained with a spectral quality greater than 20dB. Obviously, the performances of the optical source improve with the increase of the bias current, although its value will be limited for the maximum current density ($kA/cm^2$) that the active layer can resist (some ten $kA/cm^2$'s). Also, it must be pointed out that this type of optical source needs a really low threshold current ($I_{th}=17.4mA$ for $a_r=0.32$ and $L_{OA}=100\mu$m).

From the obtained results it is interesting to analyze the light-current characteristic and the spectral quality of the optical source for a TWOA's length equal to 100$\mu$m. In Fig.4 (in continuous line) the output optical power as a function of the bias current is represented. We can see that the threshold current is $I_{th}=17.4mA$ and the curve has a slope of 0.12mW/mA. Some values of the SQ have been calculated for different bias currents. For example, for $I=30mA$, values of SQ=23.5 dB and $P_{out}$=1.5 mW have been obtained. This power, due to the high value of SQ, corresponds practically to the lasing mode ($A_{th}=1.52\mu$m). Then, it can be said the source is monomode.

5. Conclusions

The computational method developed by D.Marcuse has been used in this paper to achieve the computer simulations of the optical source shown in fig.1. The obtained results demonstrate the high performances that an optical source designed starting from the external feedback of a travelling wave laser amplifier can offer. We have seen that TWOA's lengths and values of the feedback factor that optimize the proposed design exist. To be exact, for $L_{OA}=100\mu$m, $a_r=0.32$ and $I=30mA$, we have an optical source that brings, theoretically, an output power of 1.5 mW with a spectral quality over 23 dB and a threshold current around 17mA. The fact that the lasing mode is 200 times greater than the first lateral mode guarantee the monomode behaviour of the proposed optical source.

6. References


